

ESPROS Photonics Corporation Key Technology of the 21st Century

High Speed, Backside Illuminated 1024x1 Line Imager with Charge Domain Frame Store in Espros Photonic CMOS™ Technology

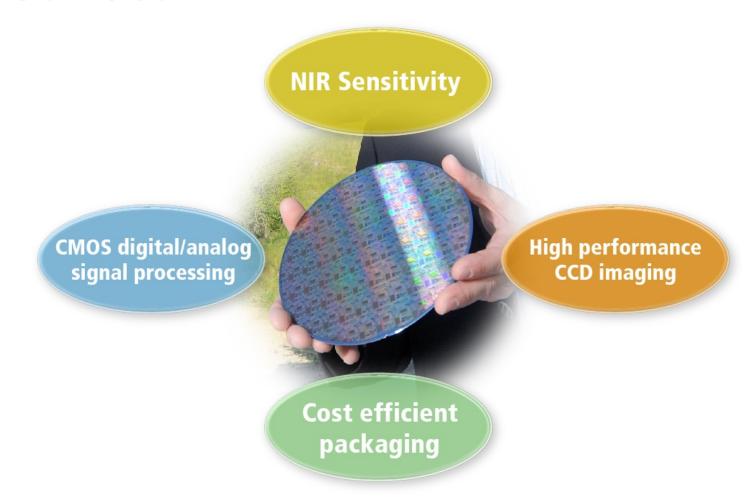
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Espros Photonics AG, Sankt Galler Strasse 135, CH-7320 Sargans, Switzerland





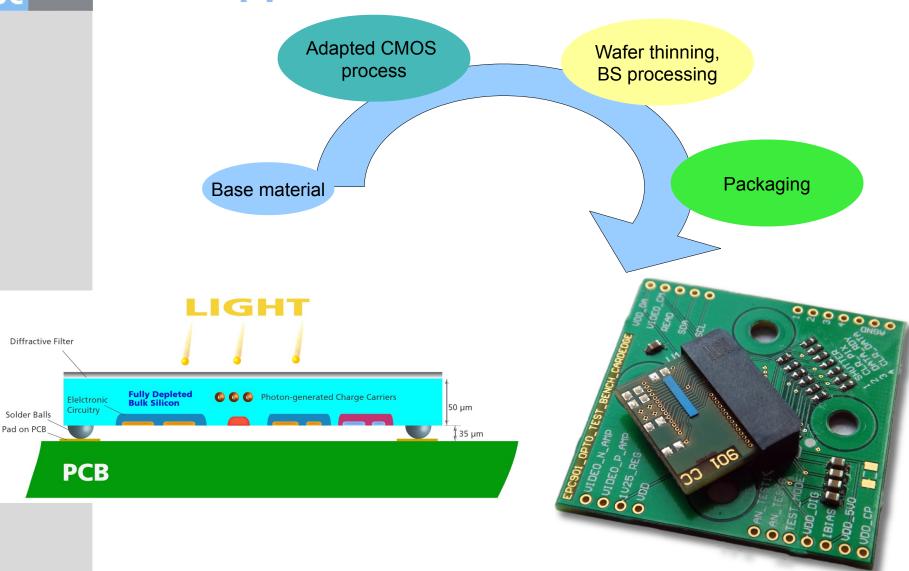
Our Goal



Provide high performance yet cost efficient solutions for special imaging applications

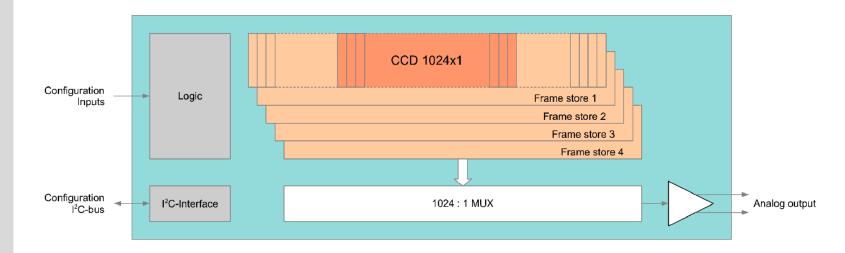


Our approach





The application



Key requirements:

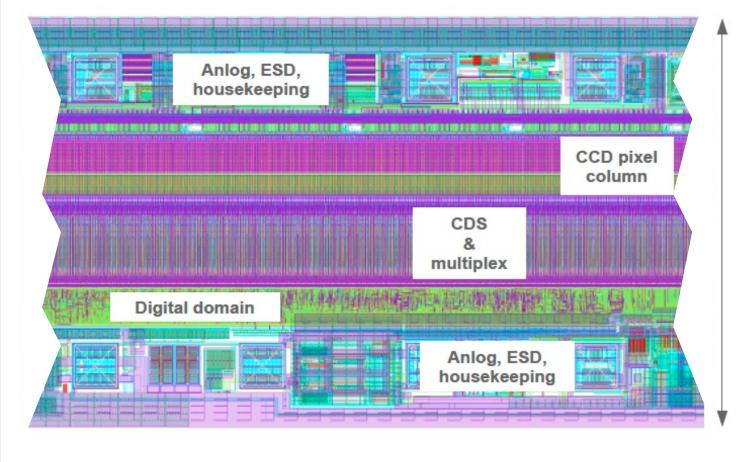
1024 pixels: 7.5μm x 120μm

Single analog video out up to 50klines/s

High-speed frame store: burst rate 500klines/s



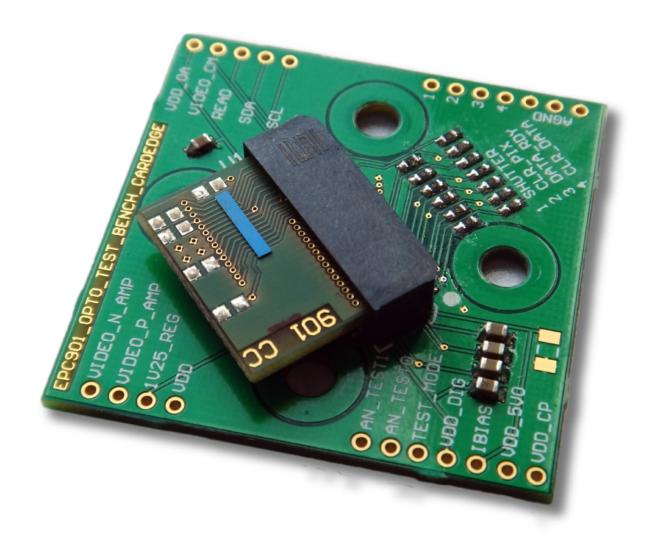
The product



7960µm

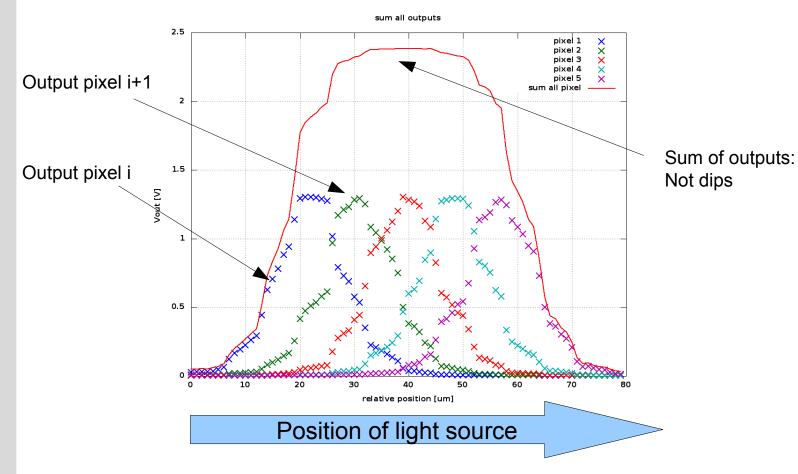


The product





The Pixel: Fill factor



Scan point light source across pixel field: No dips in summed intensity observed ==> 100% fill factor



0.9

8.0

0.7

0.6

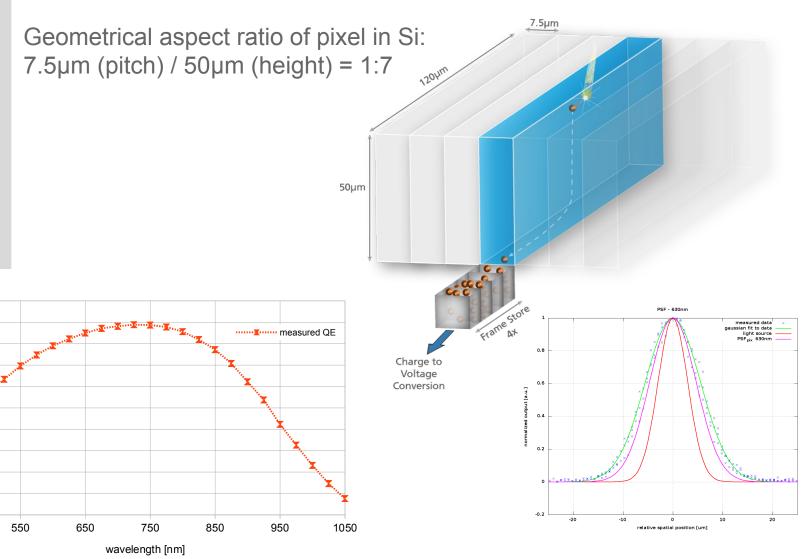
0.5 0.4 0.3 0.2 0.1

450

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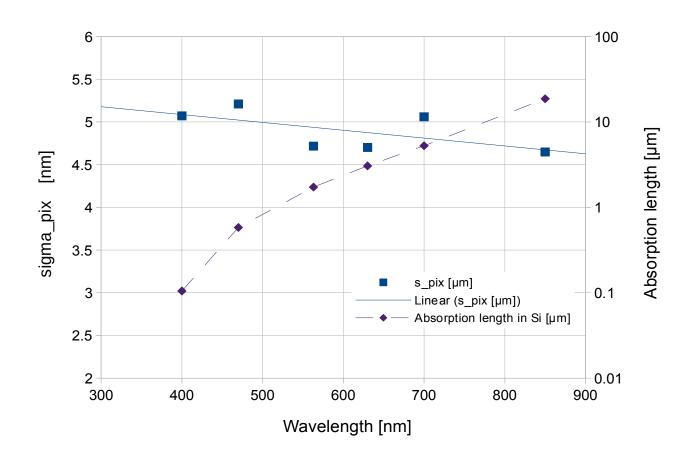
absolute quantum efficiency

The Pixel: QE & resolution





Resolution vs. wavelength

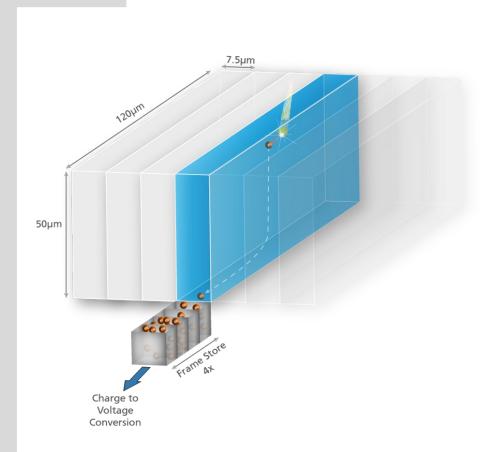


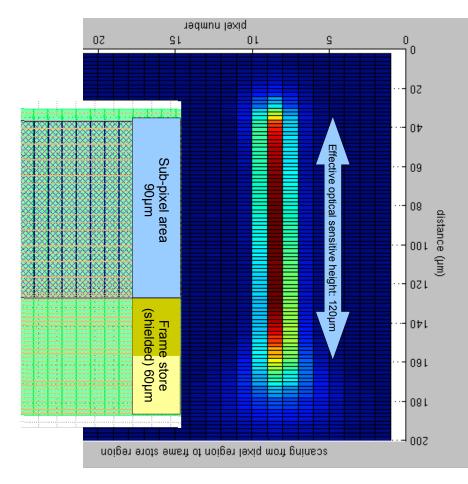
Spatial resolution is constant over wide wavelength range

→ high-res NIR imaging becomes possible



Frame store: Resolution

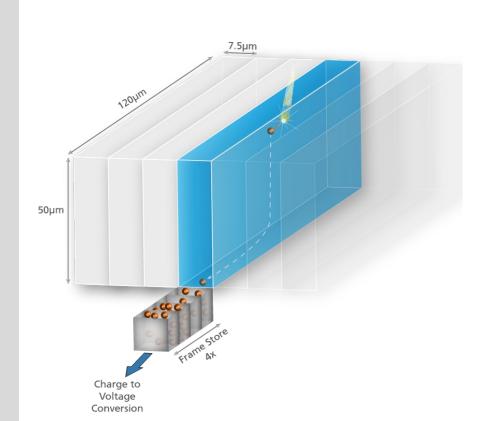


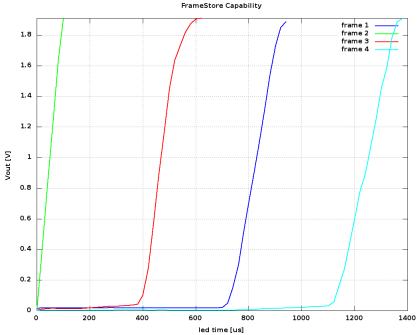


No impact on resolution by charge collection close to frame store



Frame store: Parasitic light sensitivity





No impact by illumination in FS area up to 7x max. signal amplitude Limiting factor: charge spill-over



Summary

CMOS-CCD technology with backside illumination

High-QE over broad wavelength range

Application example: Line imager

Charge domain frame store

Constant PSF from blue to NIR

Other applications can be adressed

Thank you!



epo

espros photonics corporation

more Info ...
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